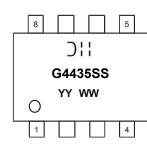


#### **Marking Information**



DI⊨ Manufacturer's Marking G4435SS = Product Type Marking Code YYWW = Date Code Marking YY or YY = Year (ex: 20 = 2020) WW or <u>WW</u>= Week (01 to 53)

### Maximum Ratings (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characte	Symbol	Value	Unit		
Drain-Source Voltage			V <sub>DSS</sub>	-30	V
Gate-Source Voltage			V <sub>GSS</sub>	±25	V
Continuous Drain Current (Note 5) $V_{GS}$ = -20	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	-7.3 -5.7	А
	t < 10s	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	Ι <sub>D</sub>	-10 -7.5	А
Pulsed Drain Current (Note 6)	I <sub>DM</sub>	-80	А		

#### **Thermal Characteristics**

Characteristic	Symbol	Value	Unit	
Power Dissipation (Note 5)	T <sub>A</sub> = +25°C	D	2.5	W
Fower Dissipation (Note 5)	T <sub>A</sub> = +70°C	P <sub>D</sub>	1.5	W
Thermal Desistance, Junction to Ambient @ T 125°C	Steady state	D	96.5	°C/W
Thermal Resistance, Junction to Ambient @ $T_A$ = +25°C	t < 10s	R <sub>θJA</sub>	55	°C/W
Operating and Storage Temperature Range		TJ, T <sub>STG</sub>	-55 to +150	°C

 Device mounted on 1in. x 1in. FR-4 PCB with 2oz. Copper, and the testing is based on the t<10s. The value in any given application depends on the user's specific board design.</li>
Repetitive rating, pulse width limited by junction temperature. Notes:

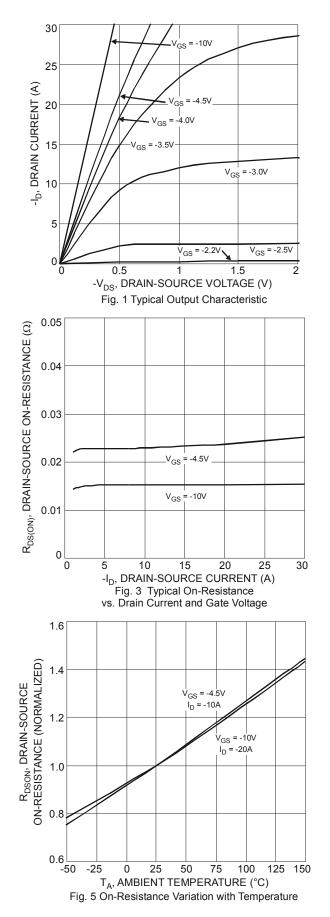


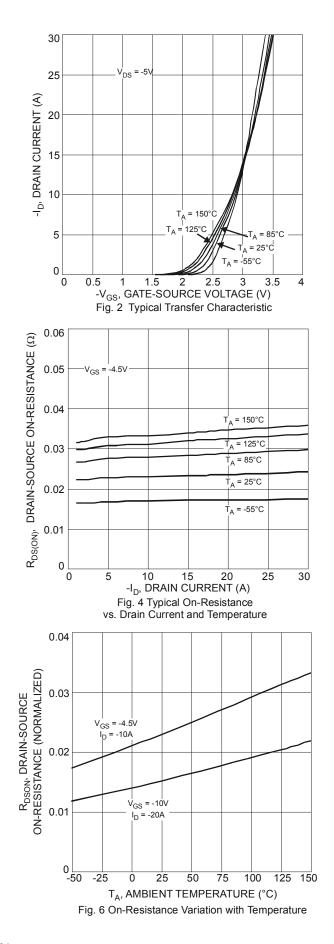
# Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

			_				
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)				1	1	1	
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-30	—	—	V	V <sub>GS</sub> = 0V, I <sub>D</sub> = -1mA	
Zero Gate Voltage Drain Current $T_J$ = +25°C	I <sub>DSS</sub>	_	—	-1.0	μA	V <sub>DS</sub> = -30V, V <sub>GS</sub> = 0V	
Gate-Source Leakage	I <sub>GSS</sub>	—	—	±100	nA	$V_{GS}$ = ±25V, $V_{DS}$ = 0V	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V <sub>GS(th)</sub>	-1.0	-1.7	-2.5	V	$V_{DS}$ = $V_{GS}$ , $I_D$ = -250 $\mu$ A	
			13	16		V <sub>GS</sub> = -20V, I <sub>D</sub> = -11A	
Static Drain-Source On-Resistance	R <sub>DS</sub> (ON)	—	15	20	mΩ	V <sub>GS</sub> = -10V, I <sub>D</sub> = -10A	
			21	29		V <sub>GS</sub> = -5V, I <sub>D</sub> = -5A	
Forward Transfer Admittance	Y <sub>fs</sub>	—	22	_	S	V <sub>DS</sub> = -5V, I <sub>D</sub> = -10A	
Diode Forward Voltage	V <sub>SD</sub>	_	-0.74	-1.0	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = -1A	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C <sub>iss</sub>	_	1614	_	pF		
Output Capacitance	C <sub>oss</sub>	_	226	_	pF	V <sub>DS</sub> = -15V, V <sub>GS</sub> = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>	_	214	_	pF		
Gate Resistance	Rg	_	6.8	_	Ω	$V_{DS}$ = 0V, $V_{GS}$ = 0V, f = 1MHz	
Total Gate Charge at 10V	Qg	_	35.4	_	nC	V <sub>GS</sub> = -10V, V <sub>DS</sub> = -15V, I <sub>D</sub> = -10A	
Total Gate Charge at 5V	Qg	_	18.9	_	nC		
Gate-Source Charge	Q <sub>gs</sub>	_	4.6		nC	V <sub>GS</sub> = -5V, V <sub>DS</sub> = -15V, I <sub>D</sub> = -10A	
Gate-Drain Charge	Q <sub>gd</sub>	_	5.7		nC		
Turn-On Delay Time	t <sub>D(on)</sub>	_	8.6		ns		
Turn-On Rise Time	tr	_	12.7	_	ns	V <sub>DS</sub> = -15V, V <sub>GS</sub> = -10V,	
Turn-Off Delay Time	t <sub>D(off)</sub>	_	44.9		ns	R <sub>L</sub> = 1.5Ω, R <sub>GEN</sub> = 3Ω	
Turn-Off Fall Time	t <sub>f</sub>	_	22.8		ns		

 Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing. Notes:

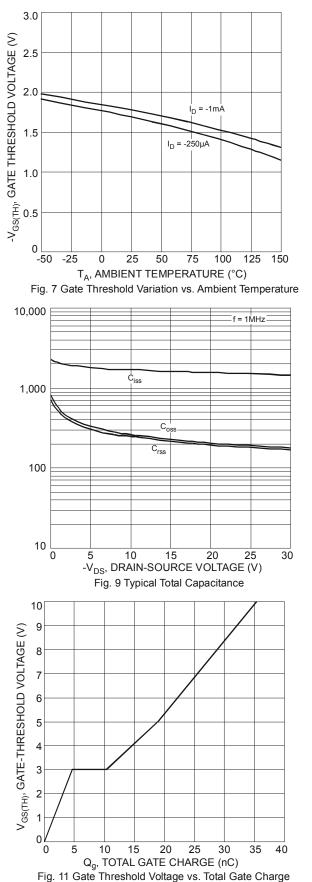


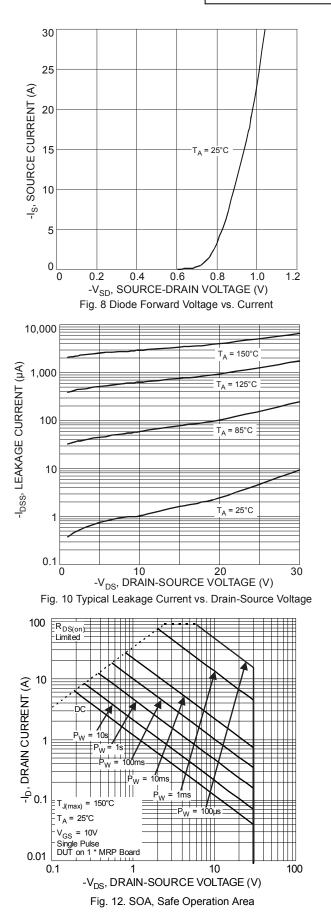




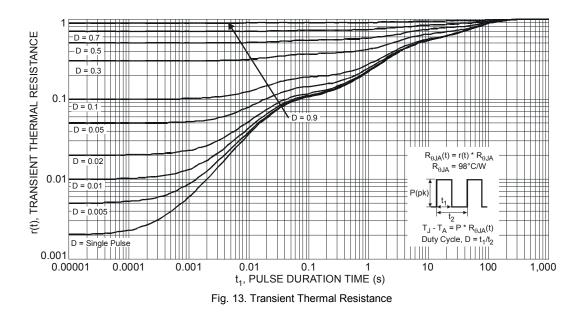








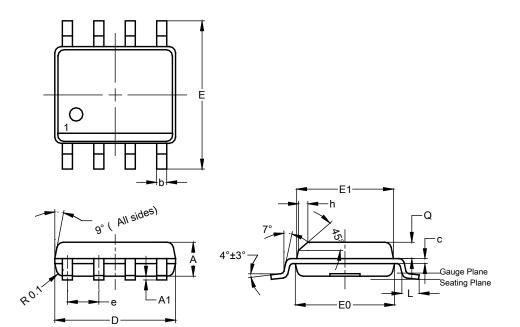






# **Package Outline Dimensions**

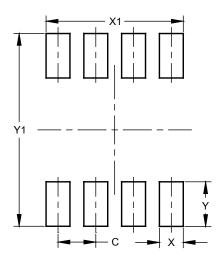
Please see http://www.diodes.com/package-outlines.html for the latest version.



	SO-8					
Dim	Min	Max	Тур			
Α	1.40	1.50	1.45			
A1	0.10	0.20	0.15			
b	0.30	0.50	0.40			
С	0.15	0.25	0.20			
D	4.85	4.95	4.90			
Е	5.90	6.10	6.00			
E1	3.80	3.90	3.85			
E0	3.85	3.95	3.90			
е			1.27			
h	-		0.35			
L	0.62	0.82	0.72			
Q	0.60	0.70	0.65			
All	All Dimensions in mm					

# Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)			
С	1.27			
Х	0.802			
X1	4.612			
Y	1.505			
Y1	6.50			



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